

Abstract Submitted
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The impact of the $^{26}\text{Al}^m(\text{p},\gamma)^{27}\text{Si}$ reaction rate on the destruction of ^{26}Al in ONe novae¹ CATHERINE DEIBEL, Yale University, JAC CAGGIANO, PNL, JASON CLARK, Yale University, RACHEL LEWIS, University of York, ANUJ PARIKH, PETER PARKER, CHRISTOPHER WREDE, Yale University — Evidence of ongoing nucleosynthesis of ^{26}Al ($\tau_{1/2} = 7.2 \times 10^5$ yr) in our galaxy has been observed in the form of the 1.809 MeV γ -ray resulting from $^{25}\text{Mg}(\text{p},\gamma)^{26}\text{Al}^{g.s.}(\beta^+\nu_e)^{26}\text{Mg}^*$ [1]. The $^{25}\text{Mg}(\text{p},\gamma)$ reaction can also produce $^{26}\text{Al}^m$, the short lived ($\tau_{1/2} = 6.3$ s), 0^+ , isomeric state of ^{26}Al , which β^+ -decays to $^{26}\text{Mg}^{g.s.}$ only and must be treated separately from $^{26}\text{Al}^{g.s.}$ at peak temperatures typical in novae ($T_9 \approx .1 - .35$)[2]. Since $^{26}\text{Al}(\text{p},\gamma)^{27}\text{Si}$ competes with the β^+ -decay of ^{26}Al in novae, resonances in $^{26}\text{Al}^{g.s./m}(\text{p},\gamma)^{27}\text{Si}$ may have a significant impact on ^{26}Al production. We have used the $^{28}\text{Si}(\text{p},\text{d})^{27}\text{Si}$, $^{28}\text{Si}({}^3\text{He},\alpha)^{27}\text{Si}^*(\text{p})^{26}\text{Al}$, and $^{27}\text{Al}({}^3\text{He},\text{t})^{27}\text{Si}^*(\text{p})^{26}\text{Al}$ reactions to study the $^{26}\text{Al}(\text{p},\gamma)^{27}\text{Si}$ reaction. Several previously unpublished levels in ^{27}Si and proton decay branching ratios will be reported. Their impact on the $^{26}\text{Al}(\text{p},\gamma)^{27}\text{Si}$ reaction rate and the nucleosynthesis of ^{26}Al in ONe novae will be discussed.

[1] Diehl, R. *et al.*, A&A, **449** (2006) 1025.

[2] Ward, R.A. and Fowler, W.A., ApJ, **238** (1980) 266.

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